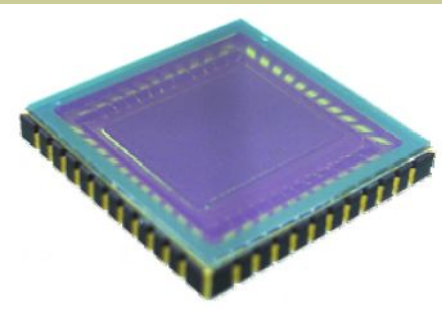


SWIR InGaAs camera

PSL has supplied Short Wave Infra Red (SWIR) cameras to end users and OEMs for the last couple of years. A selection of high responsivity InGaAs sensors, combined with low noise electronics and deep cooling, enables optimum photonic collection with best possible signal to noise ratio. Special read whilst expose mode allows 100% shutterless duty cycle and high sensitivity operation in low light level conditions.



Applications:

- Solar cell inspection
- Bare solar cell silicon wafer inspection
- Semiconductor inspection
- Astronomy
- Temperature furnace monitoring
- Industrial thermal imaging
- Imaging spectroscopy
- Dermatologic imaging
- Thick sample / tissue IR microscopy
- Laser profiling / telecom
- Low light level / range gated IR imaging

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Photonic Science Ltd

*Information /
products and
services*

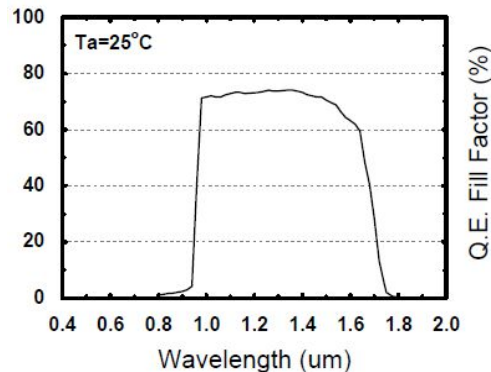


Scientific detector
systems

SWIR cameras

Photonic Science Ltd selects premium grade InGaAs sensors :

- Cooled sensors with 45 and 70 degrees C delta T, includes hermetically sealed package
- 10Mhz scanning frequencies
- Dynamic range > 1000:1
- Low dark current with less than 0.4 pA
- Gating time from milliseconds to > 500ns to 1 second
- Pixel operability: > 99.5%
- Simultaneous integration / readout enabling 100% duty cycle acquisition
- Non destructive read out
- Spectral range from 0.9 to 1.7 micron
- Video CCIR and GigE digital interface
- Air cooled / water cooled option
- Synchronisation / control : via TTL pulse
- Integrated Non Uniformity Correction, bright pixel, flat field and offset corrections



SWIR LR

- 320 (h) x 256 (v) InGaAs array
- Input pixel size : 30 x 30 microns
- Input size : 9.6 x 7.68 mm
- 25 fps at full resolution @ 10 MHz
- Responsivity in low gain mode: 0.7 μ V / electron
- Responsivity in high gain mode: 13.3 μ V / electron
- Readout noise : 120 - 150 electrons @ 10 MHz with interpolation noise reduction in high gain mode, 380 electrons in low gain mode
- Full well capacity : 150,000 electrons in high gain mode; 3,000,000 electrons in low gain mode
- Sensitivity: 10⁻¹⁰ Jones with 33ms integration time @ 1550 nm
- 16-bit extended dynamic range
- Peak QE: >70% @1100nm, > 65% from 1000 to 1600 nm
- Extended QE version up to 2.2 micron available

SWIR HR

- 640 (h) x 512 (v) InGaAs array
- Input pixel size : 25 x 25 microns
- Input size: 16 x 12.8 mm
- 25 fps at full resolution @ 10 MHz
- Responsivity in low gain mode: 1.2 μ V / electron
- Responsivity in high gain mode: 31 μ V / electron
- Readout noise : 120 - 150 electrons @ 10 MHz with interpolation noise reduction in high gain mode, 380 electrons in low gain mode
- Full well capacity : 200,000 electrons in high gain mode; 3,500,000 electrons in low gain mode
- Sensitivity: 10⁻¹⁰ Jones with 33ms integration time @ 1550 nm
- 16-bit extended dynamic range
- Peak QE: >70% @1100nm, > 65% from 1000 to 1600 nm

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